

Vishay Siliconix

P-Channel 1.8 V (G-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)		
	0.280 at V _{GS} = - 4.5 V	± 0.92		
- 8	0.380 at V _{GS} = - 2.5 V	± 0.79		
	0.530 at V _{GS} = - 1.8 V	± 0.67		

FEATURES

Marking Code

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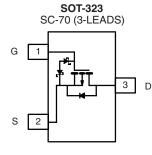
- Halogen-free According to IEC 61249-2-21
 Definition
- ESD Protection: 3000 V
- Compliant to RoHS Directive 2002/95/EC

Lot Traceability and Date Code

Part # Code



Available



Top View

Ordering Information: Si1305EDL-T1-E3 (Lead (Pb)-free) Si1305EDL-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATING	S T _A = 25 °C, ur	nless otherwi	se noted		
Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 8		v
Gate-Source Voltage		V _{GS}	± 8		
	T _A = 25 °C	I _D	± 0.92	± 0.86	
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^a$	T _A = 70 °C		± 0.74	± 0.69	
Pulsed Drain Current		I _{DM}	± 3		A
Continuous Diode Current (Diode Conduction) ^a		۱ _S	- 0.28	- 0.24	
Maximum Power Dissipation ^a	T _A = 25 °C	PD	0.34	0.29	w
Maximum Power Dissipation	T _A = 70 °C		0.22	0.19	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	t ≤ 5 s	- R _{thJA} R _{thJF}	315	375	°C/W
Maximum Junction-to-Ambient	Steady State		360	430	
Maximum Junction-to-Foot (Drain)	Steady State		285	340	

Notes:

a. Surface mounted on 1" x 1" FR4 board.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 0.45			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 4.5 V$			± 1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -6.4 \text{ V}, V_{GS} = 0 \text{ V}$			- 1		
		V_{DS} = - 6.4 V, V_{GS} = 0 V, T_{J} = 70 °C			- 5		
On-State Drain Current ^a	I _{D(on)}	V _{DS} - 5 V, V _{GS} = - 4.5 V	- 3			А	
	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 1 A		0.230	0.280		
Drain-Source On-State Resistance ^a		V _{GS} = - 2.5 V, I _D = - 0.5 A		0.315	0.380	Ω	
		V _{GS} = - 1.8 V, I _D = - 0.3 A		0.440	0.530		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 5 V, I _D = - 1 A		3.5		S	
Diode Forward Voltage ^a	V _{SD}	I _S = - 1 A, V _{GS} = 0 V			- 1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			2.6	4	nC	
Gate-Source Charge	Q _{gs}	V_{DS} = - 4 V, V_{GS} = - 4.5 V, I_D = - 1 A		0.54			
Gate-Drain Charge	Q _{gd}			0.52			
Turn-On Delay Time	t _{d(on)}			206	330		
Rise Time	t _r	V_{DD} = - 4 V, R_L = 4 Ω		431	690		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ - 1 Å, V_{GEN} = - 4.5 V, R_g = 6 Ω		1350	2160	ns	
Fall Time	t _f			1000	1600		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1 A, dl/dt = 100 A/μs		500	800		

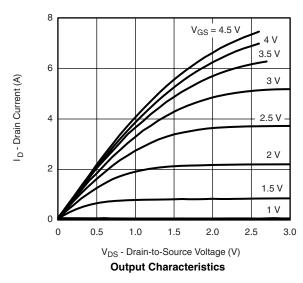
Notes:

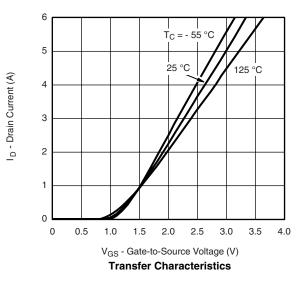
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

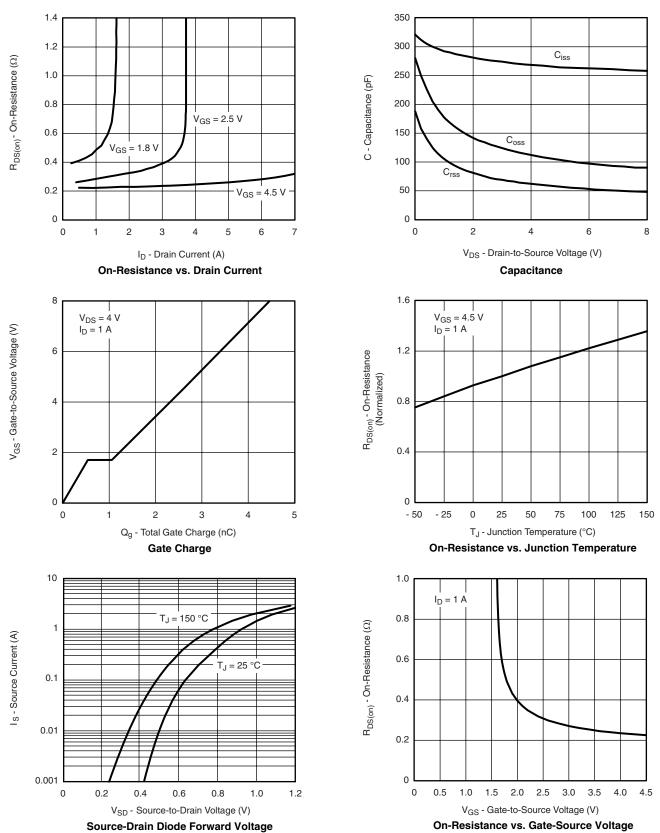






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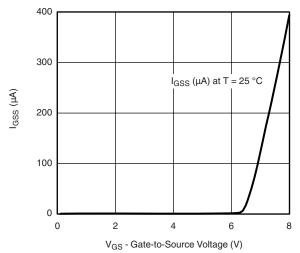


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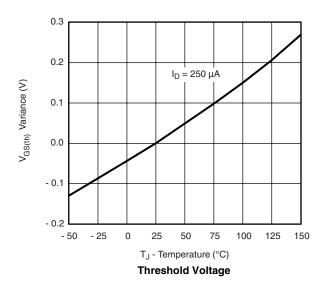


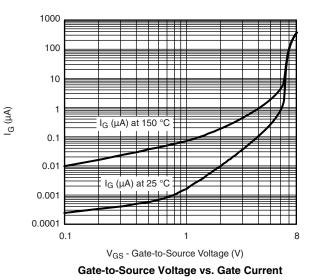
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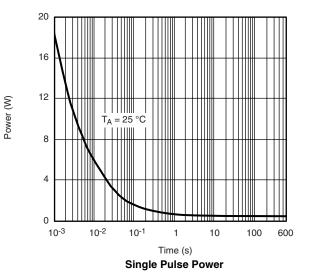
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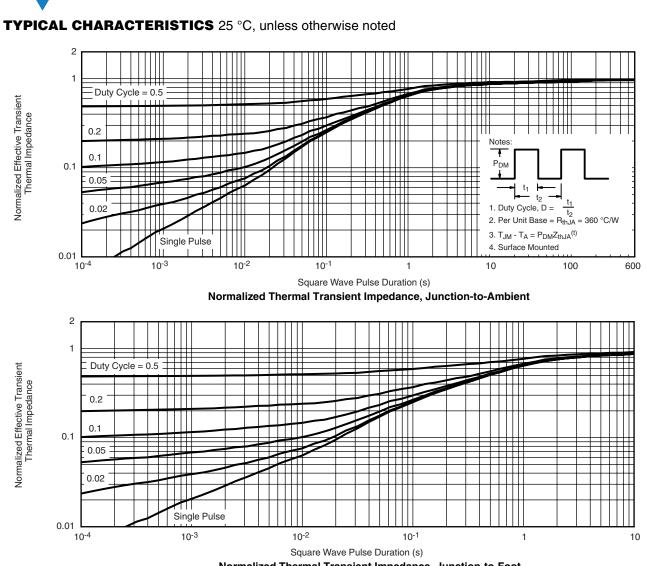


Gate-Current vs. Gate-to-Source Voltage









Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71095.

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